Ferroelectric Organic Semiconductor: Structural and Physical Properties of Alkylamide Substituted BTBT Derivatives

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[1]Benzothieno[3,2-*b*][1]-benzothiophene (BTBT) derivatives can form the 2D electronic structure and organic field-effect transistors (OFET) with high hole mobility.¹ On the other hand, alkylamide-substituted π -electronic molecules can show ferroelectric behavior

accompanying by the dipole inversion at hydrogen

Fig. 1. R-BTBT-CONHC_nH_{2n+1}

bonding (HB) sites of alkylamide units.² Such polarization change has a potential to affect the semiconducting behavior. Herein, we synthesized alkylamide-substituted R-BTBT-CONHC_nH_{2n+1} (Fig. 1), which semiconducting behavior, ferroelectricity, and molecular assembly structures were examined. Single-crystal X-ray structural analyses of 1 and 3 revealed the formation of herringbone arrangement of BTBT skeleton and the 1D HB chains of alkylamide groups (Fig. 2). The thin-films of 2 were fabricated for channel layer of a top-contact type OFET device and its μ_{FET} and V_{Th} values were observed at 0.021 cm² V^{-1} s⁻¹ and -9.7 V, respectively (Fig. 3). Based on the DSC and XRD measurements, 2 formed the SmE phase above 369 K followed by the melting at 469 K. The ferroelectric hysteresis behavior of 2 was observed in the *P*-*E* curve at the SmE phase with $E_c = 5.65$ V μ m⁻¹ and P_r = 2.21 μ C cm⁻² at 413 K and 0.1 Hz, respectively (Fig. 4).



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